

## 长春新产业光电技术有限公司

Changchun New Industries Optoelectronics Tech, Co., Ltd,

DATA SHEET

## MLL-III-1085/1~1000mW

## SPECIFICATIONS

## LOW NOISE INFRARED LASER AT 1085nm

All solid state low noise infrared laser at 1085 nm is made features of ultra compact, long lifetime, low cost and easy operating, which is used in scientific experiment, measurement, optical instrument, optical sensor, communication, spectrum analysis, etc.



Wavelength (nm)	1085±2			
Output power (mW)	>1, 5, 10, 20, , 10	>1, 5, 10, 20, , 1000		
Transverse mode	TEM <sub>00</sub>			
Operating mode	CW			
Power stability (rms, over 4 hours)	<1%, <3%, <5%			
Noise of amplitude (rms, 20Hz~20MHz)	<1%			
Warm-up time (minutes)	<10			
M <sup>2</sup> factor	<1.5			
Beam divergence, full angle (mrad)	<1.5	<1.5		
Beam diameter at 1/e <sup>2</sup> (mm)	~1.5	~1.5		
Beam height from base plate (mm)	24.8	24.8		
Pointing stability after warm-up (mrad)	<0.05	<0.05		
Operating temperature (°C)	10~35	10~35		
Power supply (90-264VAC or 5VDC)	PSU-III-LED	PSU-III-FDA	PSU-III-OEM	
Expected lifetime (hours)	10000			
Warranty	1 year			



MxL-III-1085	PSU-III-LED	PSU-III-FDA	PSU-III-OEM
140. 8(L)×73(W) ×46. 2(H) mm <sup>3</sup> , 0.6kg	153 (L) ×155(W) ×92 (H) mm <sup>3</sup> , 1.5kg	133 (L) ×130(W) ×65 (H) mm <sup>3</sup> , 1.2kg	100 (L) ×62(W) ×56 (H) mm <sup>3</sup> , 0.2kg
<sup>45</sup>	155		
415°6.5	197		